

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

Zener Voltage Regulators

500 mW SOD-123 Surface Mount

Three complete series of Zener diodes are offered in the convenient, surface mount plastic SOD-123 package. These devices provide a convenient alternative to the leadless 34-package style.

Features

- 500 mW Rating on FR-4 or FR-5 Board
- Wide Zener Reverse Voltage Range 2.4 V to 56 V
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Pb-Free Packages are Available

Mechanical Characteristics

CASE: Void-free, transfer-molded, thermosetting plastic case

FINISH: Corrosion resistant finish, easily Solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by polarity band

FLAMMABILITY RATING: UL 94 V-0

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Total Power Dissipation on FR–5 Board, (Note 1) @ T _L = 75°C Derated above 75°C	P _D	500 6.7	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	340	°C/W
Thermal Resistance, Junction-to-Lead (Note 2)	$R_{\theta JL}$	150	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

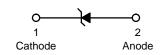
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. $FR-5 = 3.5 \times 1.5$ inches.
- Thermal Resistance measurement obtained via infrared Scan Method.



ON Semiconductor®

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SOD-123 CASE 425 STYLE 1

MARKING DIAGRAM



xx = Device Code
M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device		Package	Shipping [†]
MMSZxxx	Γ1	SOD-123 (Pb-Free)	3000/Tape & Reel
MMSZxxx	Г3	SOD-123 (Pb-Free)	10,000/Tape & Reel

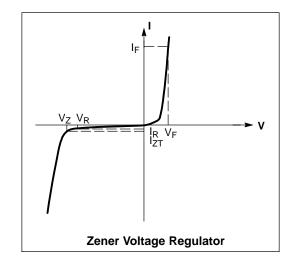
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 3 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 0.95$ V Max. @ $I_F = 10$ mA)

Symbol	Parameter
VZ	Reverse Zener Voltage @ I _{ZT}
I _{ZT}	Reverse Current
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}
I _R	Reverse Leakage Current @ V _R
V _R	Reverse Voltage
I _F	Forward Current
V _F	Forward Voltage @ I _F



ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted, $V_F = 0.9$ V Max. @ $I_F = 10$ mA)

			V _{Z1} (Volts) otes 3 and		Z _{ZT1} (Note 5)	V _{Z2} (Vo (Notes 3 a		Z_{ZT2} (Note 5)	Max R Leakage	
	Device		@ I _{ZT1}	= 5 mA		@ I _{ZT2} = 1 mA			I _R @ V _R	
Device [†]	Marking	Min	Nom	Max	Ω	Min	Max	Ω	μА	Volts
MMSZ2V4T1	T1	2.28	2.4	2.52	100	1.7	2.1	600	50	1
MMSZ2V7T1	T2	2.57	2.7	2.84	100	1.9	2.4	600	20	1
MMSZ3V0T1*	Т3	2.85	3.0	3.15	95	2.1	2.7	600	10	1
MMSZ3V3T1	T4	3.14	3.3	3.47	95	2.3	2.9	600	5	1
MMSZ3V6T1	T5	3.42	3.6	3.78	90	2.7	3.3	600	5	1
MMSZ3V9T1	U1	3.71	3.9	4.10	90	2.9	3.5	600	3	1
MMSZ4V3T1	U2	4.09	4.3	4.52	90	3.3	4.0	600	3	1
MMSZ4V7T1	U3	4.47	4.7	4.94	80	3.7	4.7	500	3	2
MMSZ5V1T1	U4	4.85	5.1	5.36	60	4.2	5.3	480	2	2
MMSZ5V6T1*	U5	5.32	5.6	5.88	40	4.8	6.0	400	1	2
MMSZ6V2T1*	V1	5.89	6.2	6.51	10	5.6	6.6	150	3	4
MMSZ6V8T1	V2	6.46	6.8	7.14	15	6.3	7.2	80	2	4
MMSZ7V5T1	V3	7.13	7.5	7.88	15	6.9	7.9	80	1	5
MMSZ8V2T1	V4	7.79	8.2	8.61	15	7.6	8.7	80	0.7	5
MMSZ9V1T1	V5	8.65	9.1	9.56	15	8.4	9.6	100	0.5	6
MMSZ10T1	A1	9.50	10	10.50	20	9.3	10.6	150	0.2	7
MMSZ11T1	A2	10.45	11	11.55	20	10.2	11.6	150	0.1	8
MMSZ12T1	А3	11.40	12	12.60	25	11.2	12.7	150	0.1	8
MMSZ13T1	A4	12.35	13	13.65	30	12.3	14.0	170	0.1	8
MMSZ15T1	A5	14.25	15	15.75	30	13.7	15.5	200	0.05	10.5
MMSZ16T1	X1	15.20	16	16.80	40	15.2	17.0	200	0.05	11.2
MMSZ18T1	X2	17.10	18	18.90	45	16.7	19.0	225	0.05	12.6
MMSZ20T1	Х3	19.00	20	21.00	55	18.7	21.1	225	0.05	14
MMSZ22T1	X4	20.90	22	23.10	55	20.7	23.2	250	0.05	15.4
MMSZ24T1	X5	22.80	24	25.20	70	22.7	25.5	250	0.05	16.8

The type numbers shown have a standard tolerance of ±5% on the nominal Zener Voltage.
 Tolerance and Voltage Designation: Zener Voltage (V_Z) is measured with the Zener Current applied for PW = 1 ms.
 Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the AC current applied.
 The specified limits are for I_{Z(AC)} = 0.1 I_{Z(DC)}, with the AC frequency = 1 kHz.
 †The "G" suffix indicates Pb–Free package available.

 *Not Available in the 10,000/Tape & Reel.

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted, $V_F = 0.9$ V Max. @ $I_F = 10$ mA)

		V _{Z1} (Volts) (Notes 6 and 7)		Z _{ZT1} (Note 8)	V _{Z2} (Volts) (Notes 6 and 7)		Z _{ZT2} (Note 8)	Max Reverse Leakage Current		
	Device		@ I _{ZT1}	= 2 mA	nA @ I _{ZT2} = 0.1 mA).1 mA	@ I _{ZT2} = 0.5 mA		
Device [†]	Marking	Min	Nom	Max	Ω	Min	Max	Ω	μΑ	Volts
MMSZ27T1	Y1	25.65	27	28.35	80	25	28.9	300	0.05	18.9
MMSZ30T1*	Y2	28.50	30	31.50	80	27.8	32	300	0.05	21
MMSZ33T1	Y3	31.35	33	34.65	80	30.8	35	325	0.05	23.1
MMSZ36T1*	Y4	34.20	36	37.80	90	33.8	38	350	0.05	25.2
MMSZ39T1*	Y5	37.05	39	40.95	130	36.7	41	350	0.05	27.3
MMSZ43T1*	Z1	40.85	43	45.15	150	39.7	46	375	0.05	30.1
MMSZ47T1	Z2	44.65	47	49.35	170	43.7	50	375	0.05	32.9
MMSZ51T1*	Z3	48.45	51	53.55	180	47.6	54	400	0.05	35.7
MMSZ56T1	Z4	53.20	56	58.80	200	51.5	60	425	0.05	39.2

^{6.} The type numbers shown have a standard tolerance of $\pm 5\%$ on the nominal Zener Voltage.

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†The "G" suffix indicates Pb–Free package available.
*Not Available in the 10,000/Tape & Reel.

TYPICAL CHARACTERISTICS

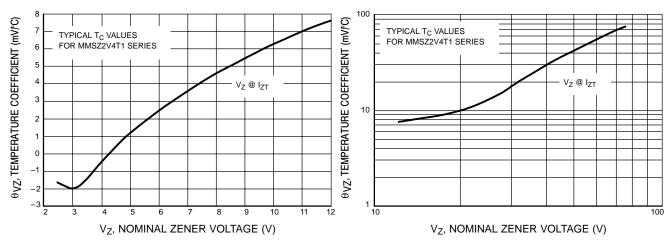


Figure 1. Temperature Coefficients (Temperature Range -55°C to +150°C)

Figure 2. Temperature Coefficients (Temperature Range –55°C to +150°C)

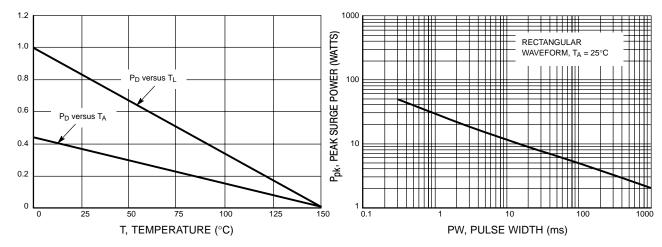


Figure 3. Steady State Power Derating

Figure 4. Maximum Nonrepetitive Surge Power

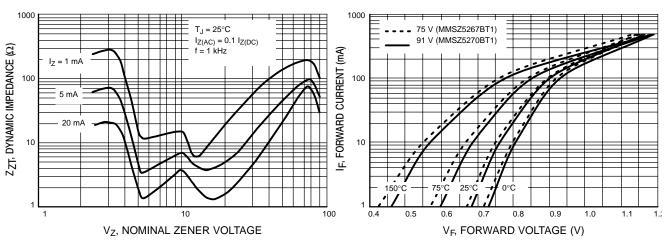


Figure 5. Effect of Zener Voltage on Zener Impedance

Figure 6. Typical Forward Voltage

TYPICAL CHARACTERISTICS

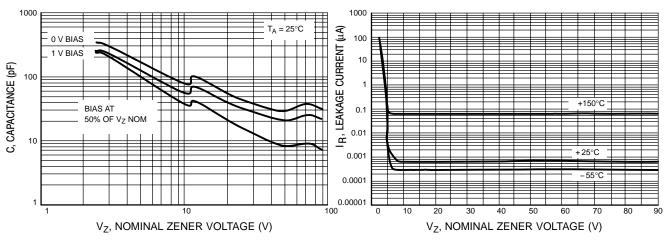


Figure 7. Typical Capacitance

Figure 8. Typical Leakage Current

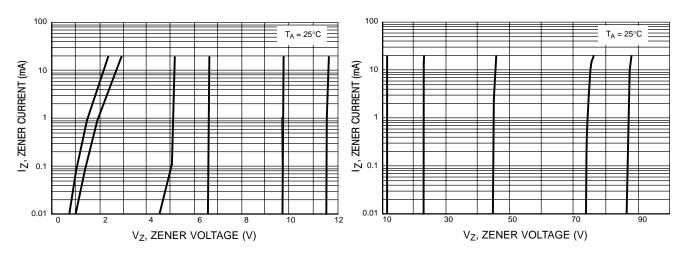
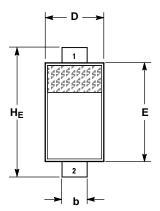


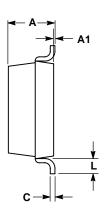
Figure 9. Zener Voltage versus Zener Current (V_Z Up to 12 V)

Figure 10. Zener Voltage versus Zener Current (12 V to 91 V)

PACKAGE DIMENSIONS

SOD-123 CASE 425-04 ISSUE E



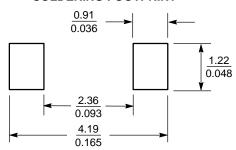


- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	M	ILLIMETE	RS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.94	1.17	1.35	0.037	0.046	0.053	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
b	0.51	0.61	0.71	0.020	0.024	0.028	
С			0.15			0.006	
D	1.40	1.60	1.80	0.055	0.063	0.071	
E	2.54	2.69	2.84	0.100	0.106	0.112	
HE	3.56	3.68	3.86	0.140	0.145	0.152	
	0.25			0.010			

STYLE 1: PIN 1. CATHODE 2 ANODE

SOLDERING FOOTPRINT*



SCALE 10:1

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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